

# ECE311 FinalRC



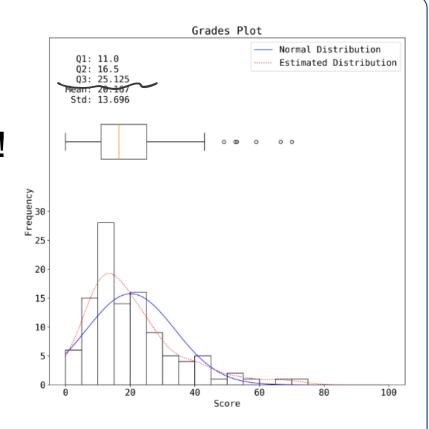


#### Before we start...



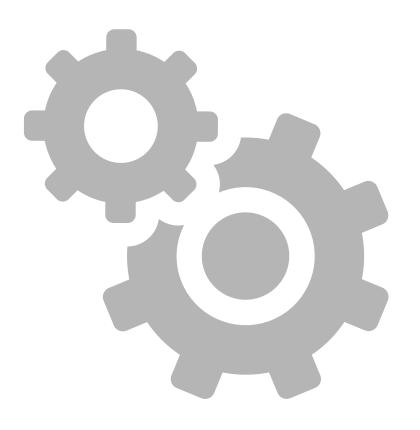
#### Reminders

- 1. Difficult exam!
- 2. Must go over all the questions!
- 3. Don't stick on one question!
- 4. More about understanding rather than calculating!



## **Contents**



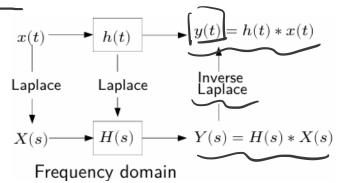


- 1 Frequency Domain
  - Bode Plot
- 3 First Order Systems
- 4 Parasitic Capacitance
- 5 Miller Effect



#### **Definition Review**

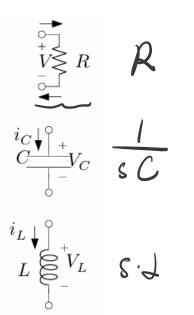
- 1. Transfer Function H(s) ViA(S) | Circuit | Out H(S) = Vout Volt.
- 2. Use S-domain to Get Time Response
- 3. Partial Fraction Expansion

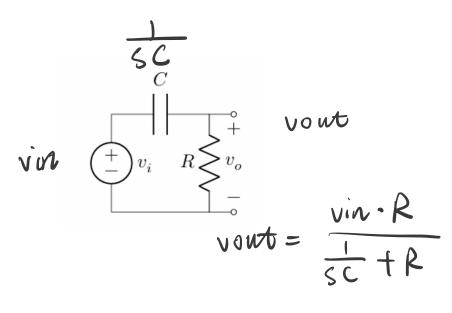




## **Definition Review**

## Capacitors and Inductors



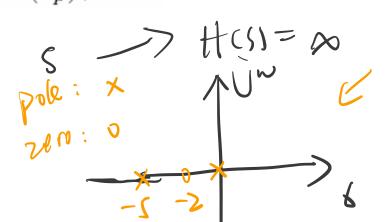




#### **Pole and Zero**

$$|H\left(s_{z}\right)|=0 \qquad \qquad \forall \left(\varsigma\right)=0$$

$$|H(s_p)| = \infty$$



$$G_{(s)} = \frac{s+2}{s^2+5s}$$

$$G(s) = \frac{s+2}{s \cdot (s+5)}$$



## **Get Diff. Eq from H(s)**

$$H(s) = 3 \frac{(s+4)}{s^2 + 2s + 5} \frac{f(s)}{\chi(s)} \qquad s^n \chi(s) \frac{1}{s^2 + 2s + 5} \frac{ds}{dx} \frac{ds}{dx}$$

$$(\frac{\zeta}{4} + 2s + 5) \cdot f(s) = 3(s + \varphi) \cdot \chi(s)$$

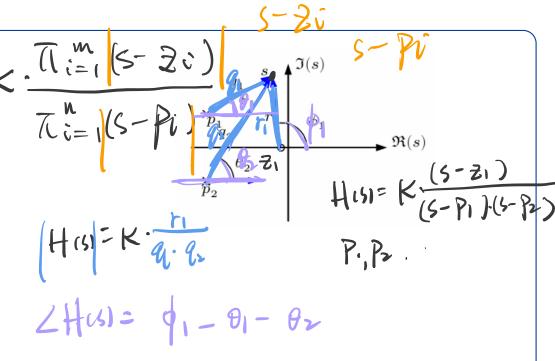
$$\frac{d^2 y(t)}{dt^2} + 2 \cdot \frac{y(t)}{dt} + y(t) = 3 \frac{d\chi(t)}{dt} + 12\chi(t)$$



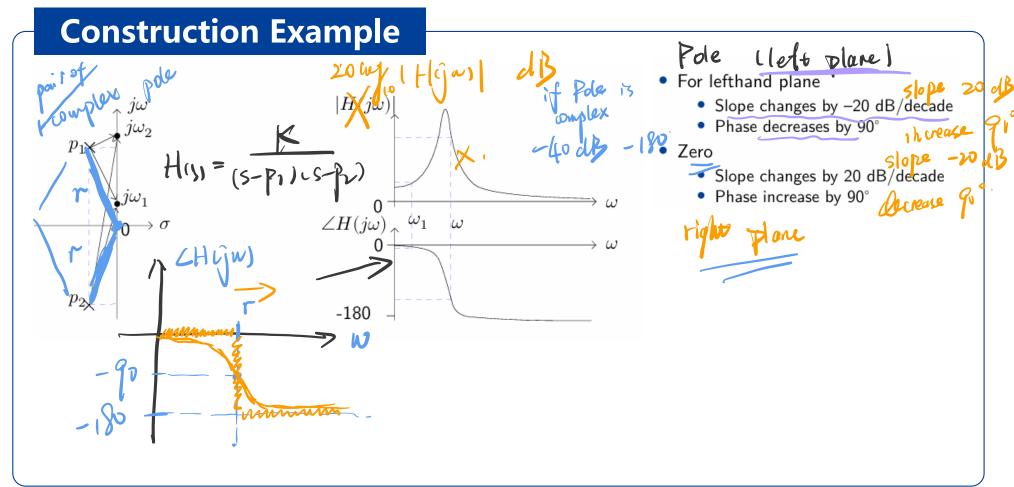
## Magnitude and Phase

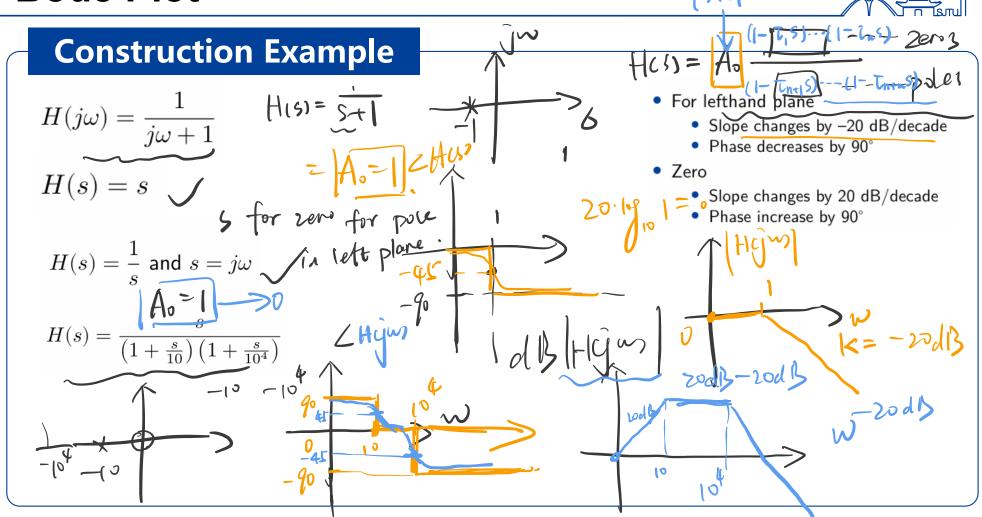
$$|H(s)| = K \frac{r_1 \dots r_m}{q_1 \dots q_n}$$

$$\angle H(s) = (\phi_1 + \ldots + \phi_m) - (\theta_1 + \ldots + \theta_n)$$



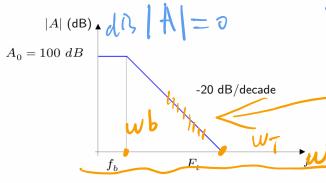








#### **Bandwidth and Gain-Bandwidth Product**



- f(t) ( $\omega_t$ ) is  $\omega$  where  $|A(j\omega)| = 1$ 
  - $A(j\omega) = \frac{A_0}{1 + j\omega/\omega_h}$  (24)
  - $1 \approx \frac{A_0}{\omega_{T/\omega_b}} \Rightarrow \omega_T \approx A_0 \omega_b \quad (25)$ 
    - (26) $\omega_T \approx A_0 \omega_b$

Recommendations for GBW calculation:

Draw the magnitude plot in dB directly to solve for

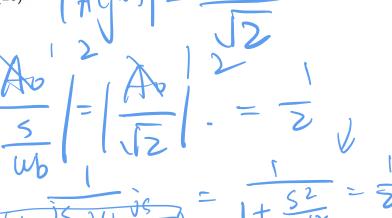
bandwidth!

Or derive the equation and set it to 1 Both are OK!

Typically only one solution is needed to be considered!

$$\frac{5^2}{Wb^2} = 1 \rightarrow \left[ 5 = Wb \right].$$

- For lefthand plane
  - Slope changes by -20 dB/decade
  - Phase decreases by 90°
- Zero
  - Slope changes by 20 dB/decade
  - Phase increase by 90°





#### **Bandwidth and Gain-Bandwidth Product**

$$V_{out}(\omega) = A(\omega)V_{Id} = A(\omega)(V_{in} - V_n) \quad V_{out} = \frac{A_0}{1 + \frac{S}{\omega b}} \quad (V_{in} - \frac{S}{\omega b})$$

$$= A(\omega)(V_{in} - \beta V_{out}) \quad A_0 = \frac{A_0}{1 + \frac{S}{\omega b}} \quad (V_{in} - \beta V_{out}) \quad A_0 = \frac{A_0}{1 + \frac{S}{\omega b}} \quad V_{in} = \frac{A_$$

## **First Order Systems**



#### **Definition**

## Contains 1 pole and at most 1 zero

$$H(S) = \frac{a_0 + a_1 S}{1 + bS}$$

$$H(s) = \frac{H^0 + H^1 \tau s}{1 + \tau s}$$

$$\tau = RC_1 \qquad \tau = \frac{L_1}{R_0}$$

To find the time constant, remove the cap/ind nulling all the sources, find the resistance.

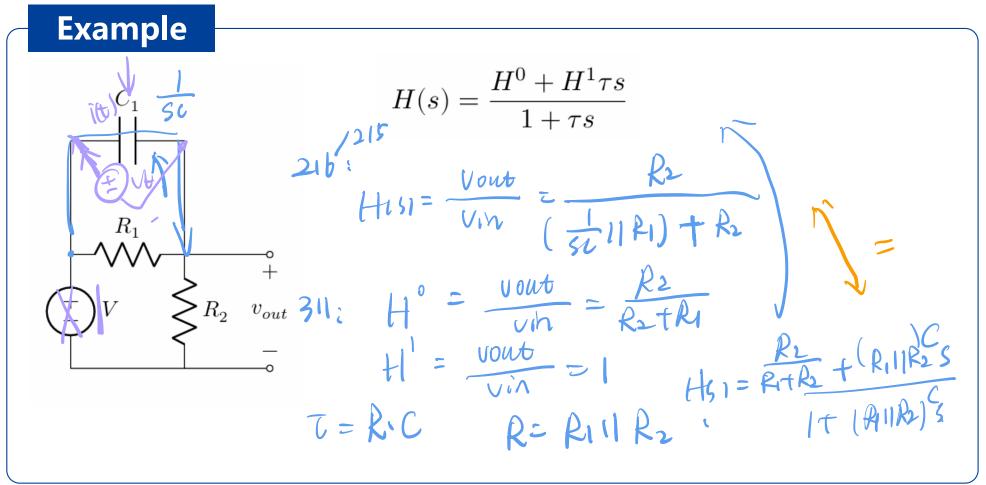
To find transfer constant  $H^0$ , it is just the low frequency gain.  $M \longrightarrow \text{short}$ 

To find the transfer constant  $H^1$ , we look into high frequency response, so the cap shall be shorted. For inductor it is the opposite.

independent source.

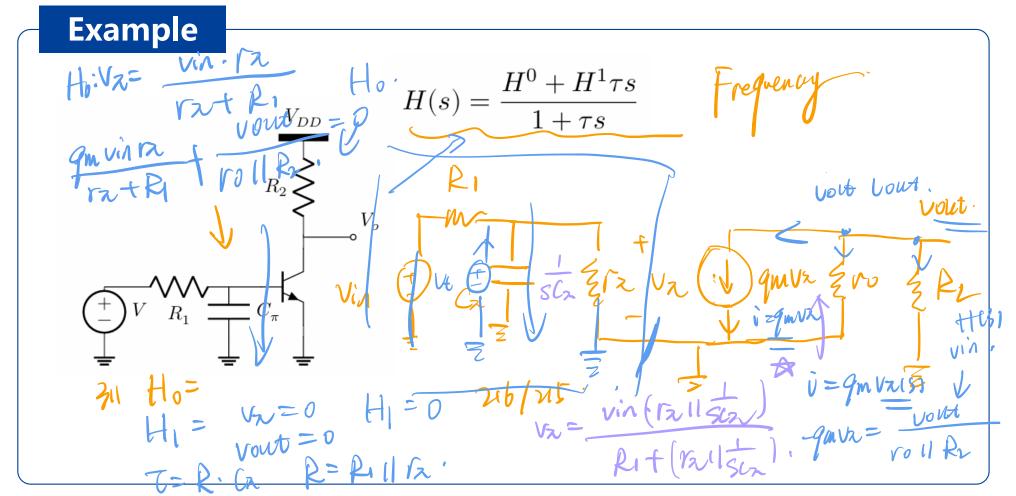
## **First Order Systems**





## **First Order Systems**



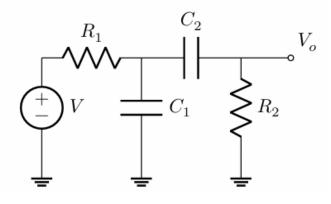


## Nth Order Systems



## **Example**

$$H(s) = \frac{a_0 + a_1 S + a_2 S^2 + \dots}{1 + b_1 S + b_2 S^2 + \dots}$$



Too hard for me to explain it explicitly...(For myself I can not understand what prof is talking about...)

Too many parameters

Suggest ECE216 methods for analyzing and work out the parameter conversely

**Tips:** the voltage and current relationship in frequency domain still holds!



#### **Bandwidth Estimation**

$$H(s) \approx \frac{a_0}{1 + b_1 s + b_2 s^2 + \cdots + b_n s^n}$$

$$H(s) \approx \frac{a_0}{1 + b_1 s}$$

$$\omega_h \approx \frac{1}{b_1} = \frac{1}{\sum_{i=1}^{N} \tau_i^0}$$

## **Parasitic Capacitance**



#### **Definition**

#### Triode

$$C_{GS} = W_{ov} + 1/2 (WLC_{ox})$$
 (1)

$$C_{CD} = WC_{ov} + 1/2 (WLC_{ov})$$
 (2)

$$C_{GD} = WC_{ov} + 1/2 (WLC_{ox})$$
 (2)



$$C_{GS} = WC_{ov} + 2/3 (WLC_{ox})$$
 (5)

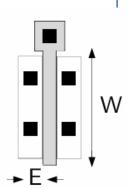
$$C_{GD} = WC_{ov} \tag{6}$$

$$C_{SB} = WEC_{j} + 2(W + E)C_{jsw}$$
 (3)

$$C_{DB} = WEC_j + 2(W+E)C_{jsw}$$
 (4)

$$C_{SB} = WC_j + 2(W + E)C_{jsw}$$
 (7)

$$C_{DB} = WEC_j + 2(W+E)C_{jsw}$$
 (8)



## Parasitic Capacitance



#### **Parameter**

NMOS Model  
LEVEL = 1  
NSUB = 
$$9e + 14$$
  
TOX =  $9e - 9$   
MJ =  $0.45$   
PMOS Model  
LEVEL = 1  
NSUB =  $5e + 14$ 

MJ = 0.5

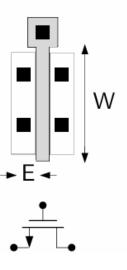
VTO = 0.7

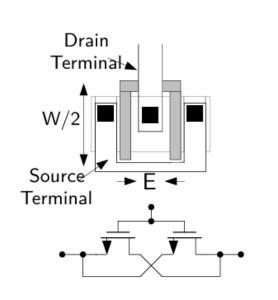
## **Parasitic Capacitance**



## **Example**

#### **NMOS**





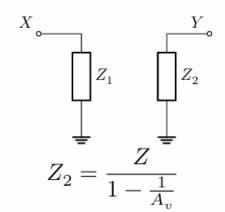
## Miller Effect



## **Definition**

$$X \stackrel{Z}{\smile} Y$$

$$Z_1 = \frac{Z}{1 - A_v} \tag{31}$$

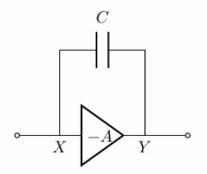


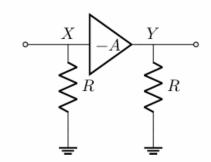
Note: There must be another way between X and Y

## **Miller Effect**



## **Example**





$$Z_1 = \frac{\frac{1}{SC_F}}{1+A} = \frac{1}{S(1+A)C_F}$$

$$Z_2 = \frac{\frac{1}{SC_F}}{1 + \frac{1}{A}} = \frac{1}{S\left(1 + \frac{1}{A}\right)C_F}$$

## **Miller Effect**



## **Example**

#### Output impedance

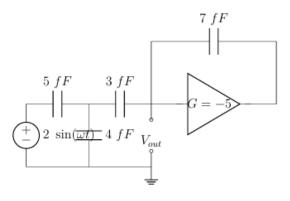


Figure 2: Miller



# Thanks!



